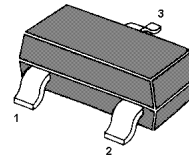
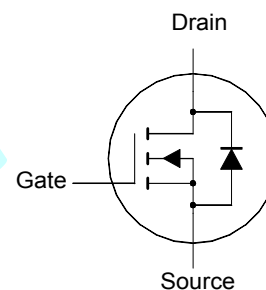


## MMFTN123 N-Channel Logic Level Enhancement Mode Field Effect Transistor



1. Gate 2. Source 3. Drain  
SOT-23 Plastic Package



### Absolute Maximum Ratings ( $T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	$V_{DSS}$	100	V
Gate-Source Voltage	$V_{GSS}$	$\pm 20$	V
Drain Current	$I_D$	170	mA
Peak Drain Current	$I_{DM}$	680	mA
Total Power Dissipation	$P_{tot}$	360	mW
Junction Temperature	$T_j$	150	$^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	-65 to +150	$^\circ\text{C}$

### Thermal Characteristics

Parameter	Symbol	Value	Unit
Thermal Resistance from Junction to Ambient	$R_{thj-a}$	347	K/W

**Characteristics at  $T_a = 25^\circ\text{C}$  unless otherwise specified**

Parameter	Symbol	Min.	Typ.	Max.	Unit
Drain-Source Breakdown Voltage at $I_D = 250\ \mu\text{A}$	$V_{(BR)DSS}$	100	-	-	V
Gate-Source Threshold Voltage at $V_{GS} = V_{DS}$ , $I_D = 1\ \text{mA}$	$V_{GSth}$	0.8	-	2	V
Drain-Source Leakage Current at $V_{DS} = 100\ \text{V}$ at $V_{DS} = 20\ \text{V}$	$I_{DSS}$	- -	- -	1 10	$\mu\text{A}$ nA
Gate-Source Leakage Current at $V_{GS} = \pm 20\ \text{V}$	$I_{GSS}$	-	-	$\pm 50$	nA
Drain-Source On-State Resistance at $V_{GS} = 10\ \text{V}$ , $I_D = 170\ \text{mA}$ at $V_{GS} = 4.5\ \text{V}$ , $I_D = 170\ \text{mA}$	$R_{DS(ON)}$	- -	- -	6 10	$\Omega$
Input Capacitance at $V_{DS} = 25\ \text{V}$ , $f = 1\ \text{MHz}$	$C_{iss}$	-	73	-	pF
Output Capacitance at $V_{DS} = 25\ \text{V}$ , $f = 1\ \text{MHz}$	$C_{oss}$	-	7	-	pF
Reverse Transfer Capacitance at $V_{DS} = 25\ \text{V}$ , $f = 1\ \text{MHz}$	$C_{rss}$	-	3.4	-	pF
Turn-On Delay Time at $V_{DD} = 30\ \text{V}$ , $I_D = 280\ \text{mA}$ , $V_{GS} = 10\ \text{V}$ , $R_G = 6\ \Omega$	$t_{d(on)}$	-	-	3.4	ns
Turn-On Rise Time at $V_{DD} = 30\ \text{V}$ , $I_D = 280\ \text{mA}$ , $V_{GS} = 10\ \text{V}$ , $R_G = 6\ \Omega$	$t_r$	-	-	18	ns
Turn-Off Delay Time at $V_{DD} = 30\ \text{V}$ , $I_D = 280\ \text{mA}$ , $V_{GS} = 10\ \text{V}$ , $R_G = 6\ \Omega$	$t_{d(off)}$	-	-	31	ns
Turn-Off Fall Time at $V_{DD} = 30\ \text{V}$ , $I_D = 280\ \text{mA}$ , $V_{GS} = 10\ \text{V}$ , $R_G = 6\ \Omega$	$t_f$	-	-	5	ns

## PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT-23

